





#### P-CHANNEL ENHANCEMENT MODE MOSFET

## **Product Summary**

BV <sub>DSS</sub>	RDS(ON) max	I <sub>D</sub> T <sub>A</sub> = +25°C
	$45 \text{m}\Omega @ V_{GS} = -4.5V$	-4.3A
-20V	$58m\Omega @ V_{GS} = -2.5V$	-3.8A
	$90m\Omega @ V_{GS} = -1.8V$	-3.1A

### **Description**

This new generation MOSFET is designed to minimize the on-state resistance ( $R_{DS(ON)}$ ) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

# **Applications**

- DC-DC Converters
- Power Management Functions

### **Features**

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMP2045UQ is suitable for automotive applications requiring specific change control; it is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.
- https://www.diodes.com/quality/product-definitions/

#### **Mechanical Data**

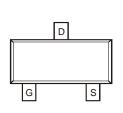
- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
   Solderable per MIL-STD-202, Method 208 (3)
- Terminals Connections: See Diagram Below
- Weight: 0.009 grams (Approximate)



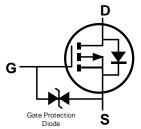


SOT23

Top View







Equivalent Circuit

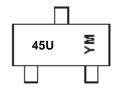
### Ordering Information (Note 4)

Part Number	Compliance	Case	Packaging
DMP2045UQ-7	Automotive	SOT23	3,000/Tape & Reel
DMP2045UQ-13	Automotive	SOT23	10,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**



 $45U = Product Type Marking Code YM or <math>\overline{Y}M = Date Code Marking Y or \overline{Y} = Year (ex: G = 2019) M = Month (ex: 9 = September)$ 

Date Code Key

	Year	2019		2020	2021		2022	2023		2024	2025		2026
	Code	G		Н			J	K		L	М		N
ſ	Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
ſ	Code	1	2	3	4	5	6	7	8	9	0	N	D



# 

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	$V_{DSS}$	-20	V		
Gate-Source Voltage	$V_{GSS}$	±8	V		
Continuous Drain Current (Note 6) $V_{GS} = -4.5V$ Steady $T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$			I <sub>D</sub>	-4.3 -3.5	А
Maximum Continuous Body Diode Forward Current (	Is	-1.2	Α		
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I <sub>DM</sub>	-25	A		

### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)		P <sub>D</sub>	0.8	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{\theta JA}$	154	°C/W
Total Power Dissipation (Note 6)		P <sub>D</sub>	1.2	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{\theta JA}$	98	°C/W
Operating and Storage Temperature Range	•	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

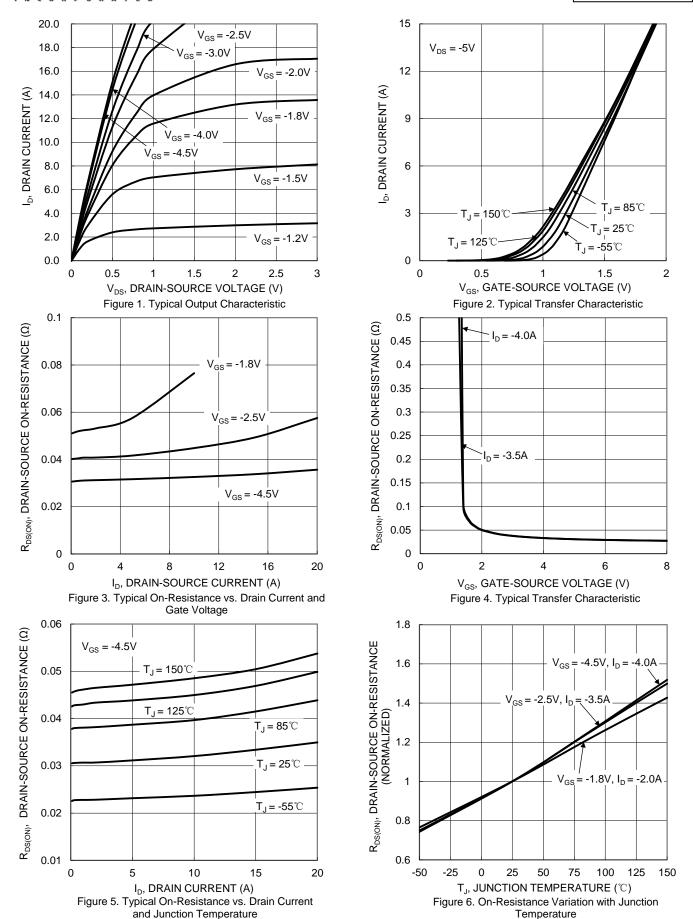
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-20	_	_	V	V <sub>GS</sub> = 0V, I <sub>D</sub> = -250μA
Zero Gate Voltage Drain Current T <sub>J</sub> = +25°C	I <sub>DSS</sub>	_	_	-1	μΑ	V <sub>DS</sub> = -20V, V <sub>GS</sub> = 0V
Gate-Source Leakage	I <sub>GSS</sub>	_	_	±10	μΑ	$V_{GS} = \pm 8.0 \text{V}, V_{DS} = 0 \text{V}$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	-0.3	_	-1.0	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$
		_	32	45		V <sub>GS</sub> = -4.5V, I <sub>D</sub> = -4.0A
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	_	42	58	mΩ	V <sub>GS</sub> = -2.5V, I <sub>D</sub> = -3.5A
		_	54	90		V <sub>GS</sub> = -1.8V, I <sub>D</sub> = -1.0A
Diode Forward Voltage	V <sub>SD</sub>		-0.7	-1.2	V	V <sub>GS</sub> = 0V, I <sub>S</sub> = -1.0A
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss	_	634	_	pF	
Output Capacitance	Coss	_	81	_	pF	$V_{DS} = -10V, V_{GS} = 0V$ f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	66	_	pF	1 – 1.000112
Gate Resistance	Rg	_	20	_	Ω	V <sub>DS</sub> = 0V, V <sub>GS</sub> = 0V, f = 1.0MHz
Total Gate Charge	Qg	_	6.8	_	nC	
Gate-Source Charge	Q <sub>gs</sub>	_	0.7	_	nC	$V_{GS} = -4.5V, V_{DS} = -10V$ $I_{D} = -4A$
Gate-Drain Charge	Q <sub>gd</sub>	_	1.6	_	nC	ID = -4A
Turn-On Delay Time	t <sub>D(ON)</sub>	_	4.2	_	ns	
Turn-On Rise Time	t <sub>R</sub>	_	3.4	_	ns	V <sub>DD</sub> = -10V, V <sub>GS</sub> = -4.5V,
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	23	_	ns	$R_L = 3.3\Omega$ , $R_G = 1\Omega$
Turn-Off Fall Time	t <sub>F</sub>	_	9.6	_	ns	
Reverse Recovery Time	t <sub>RR</sub>	_	1.8	_	ns	I <sub>F</sub> = -1.0A, di/dt = 100A/μs
Reverse Recovery Charge	Q <sub>RR</sub>	_	9.4	_	nC	I <sub>F</sub> = -1.0A, di/dt = 100A/μs

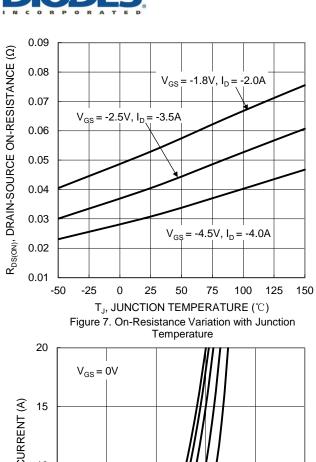
Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.

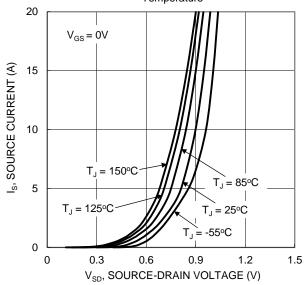
<sup>7.</sup> Short duration pulse test used to minimize self-heating effect.
8. Guaranteed by design. Not subject to product testing.

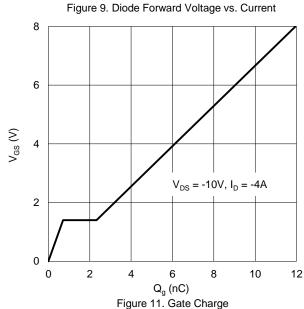












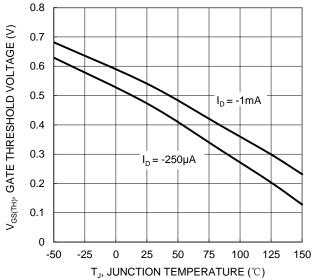
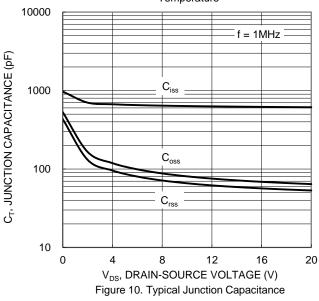
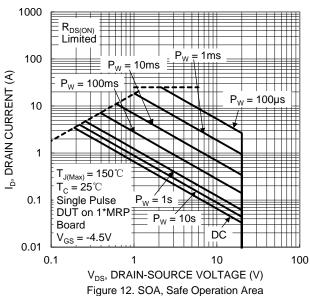
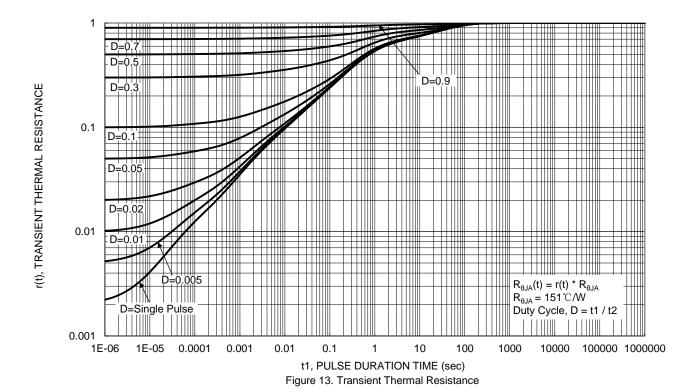


Figure 8. Gate Threshold Variation vs. Junction Temperature









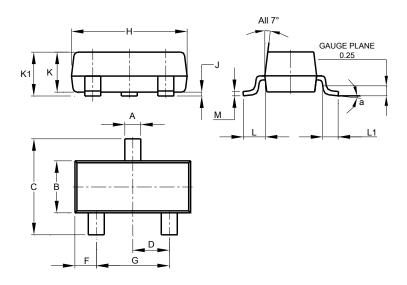
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# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23

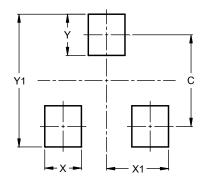


SOT23							
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
С	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
<b>H</b> 2.80		3.00	2.90				
<b>J</b> 0.013		0.10	0.05				
<b>K</b> 0.890		1.00	0.975				
K1	0.903	1.10	1.025				
L	0.45	0.61	0.55				
L1	0.25	0.55	0.40				
М	<b>M</b> 0.085		0.110				
а	<b>a</b> 0°						
All Dimensions in mm							

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### SOT23



Dimensions	Value (in mm)
C	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9



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